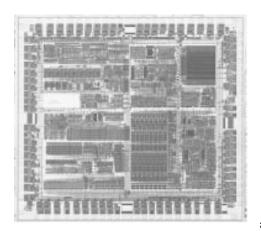
intal 80C186XL/80C188XL **16-BIT HIGH-INTEGRATION EMBEDDED PROCESSORS**

- Low Power, Fully Static Versions of 80C186/80C188
- Operation Modes:
 - Enhanced Mode
 - **DRAM Refresh Control Unit**
 - Power-Save Mode
 - Direct Interface to 80C187 (80C186XL Only)
 - Compatible Mode
 - NMOS 80186/80188 Pin-for-Pin **Replacement for Non-Numerics** Applications
- Integrated Feature Set
 - Static, Modular CPU
 - Clock Generator
 - 2 Independent DMA Channels
 - Programmable Interrupt Controller
 - 3 Programmable 16-Bit Timers
 - Dynamic RAM Refresh Control Unit - Programmable Memory and
 - **Peripheral Chip Select Logic**
 - Programmable Wait State Generator
 - Local Bus Controller
 - Power-Save Mode
 - System-Level Testing Support (High Impedance Test Mode)

- Completely Object Code Compatible with Existing 8086/8088 Software and Has 10 Additional Instructions over 8086/8088
- Speed Versions Available - 25 MHz (80C186XL25/80C188XL25)
 - 20 MHz (80C186XL20/80C188XL20)
 - 12 MHz (80C186XL12/80C188XL12)
- Direct Addressing Capability to 1 MByte Memory and 64 Kbyte I/O
- Available in 68-Pin:
 - Plastic Leaded Chip Carrier (PLCC)
 - Ceramic Pin Grid Array (PGA)
 - Ceramic Leadless Chip Carrier (JEDEC A Package)
- Available in 80-Pin: — Quad Flat Pack (EIAJ)
 - Shrink Quad Flat Pack (SGFP)
- Available in Extended Temperature Range (-40° C to $+85^{\circ}$ C)

The Intel 80C186XL is a Modular Core re-implementation of the 80C186 microprocessor. It offers higher speed and lower power consumption than the standard 80C186 but maintains 100% clock-for-clock functional compatibility. Packaging and pinout are also identical.



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80C186XL/80C188XL 16-Bit High-Integration Embedded Processors

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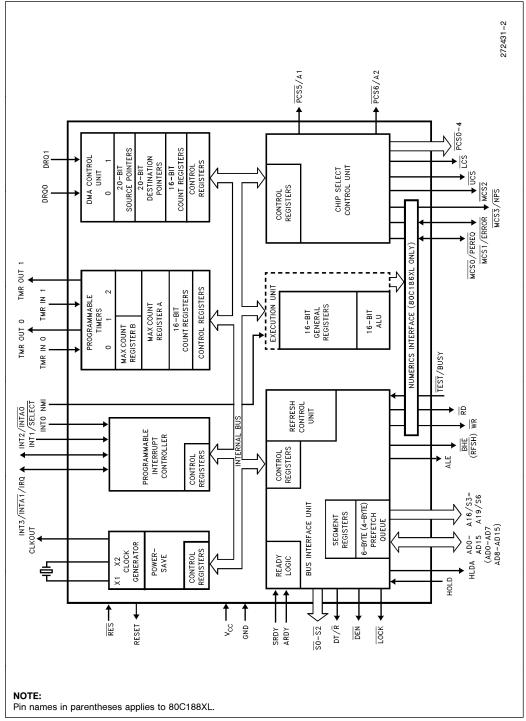


Figure 1. 80C186XL/80C188XL Block Diagram



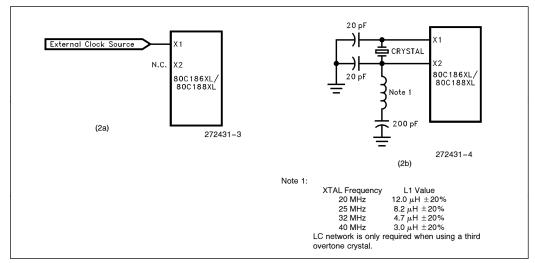


Figure 2. Oscillator Configurations (see text)

INTRODUCTION

Unless specifically noted, all references to the 80C186XL apply to the 80C188XL. References to pins that differ between the 80C186XL and the 80C188XL are given in parentheses.

The following Functional Description describes the base architecture of the 80C186XL. The 80C186XL is a very high integration 16-bit microprocessor. It combines 15–20 of the most common microprocessor system components onto one chip. The 80C186XL is object code compatible with the 8086/8088 microprocessors and adds 10 new instruction types to the 8086/8088 instruction set.

The 80C186XL has two major modes of operation, Compatible and Enhanced. In Compatible Mode the 80C186XL is completely compatible with NMOS 80186, with the exception of 8087 support. The Enhanced mode adds three new features to the system design. These are Power-Save control, Dynamic RAM refresh, and an asynchronous Numerics Coprocessor interface (80C186XL only).

80C186XL CORE ARCHITECTURE

80C186XL Clock Generator

The 80C186XL provides an on-chip clock generator for both internal and external clock generation. The clock generator features a crystal oscillator, a divideby-two counter, synchronous and asynchronous ready inputs, and reset circuitry. The 80C186XL oscillator circuit is designed to be used either with a parallel resonant fundamental or third-overtone mode crystal, depending upon the frequency range of the application. This is used as the time base for the 80C186XL.

The output of the oscillator is not directly available outside the 80C186XL. The recommended crystal configuration is shown in Figure 2b. When used in third-overtone mode, the tank circuit is recommended for stable operation. Alternately, the oscillator may be driven from an external source as shown in Figure 2a.

The crystal or clock frequency chosen must be twice the required processor operating frequency due to the internal divide by two counter. This counter is used to drive all internal phase clocks and the external CLKOUT signal. CLKOUT is a 50% duty cycle processor clock and can be used to drive other system components. All AC Timings are referenced to CLKOUT.

Intel recommends the following values for crystal selection parameters.

Temperature Range:	Application Specific
ESR (Equivalent Series Resista	nce): 60Ω max
C ₀ (Shunt Capacitance of Cryst	al): 7.0 pF max
C ₁ (Load Capacitance):	20 pF \pm 2 pF
Drive Level:	2 mW max

80C186XL/80C188XL

Bus Interface Unit

The 80C186XL provides a local bus controller to generate the local bus control signals. In addition, it employs a HOLD/HLDA protocol for relinquishing the local bus to other bus masters. It also provides outputs that can be used to enable external buffers and to direct the flow of data on and off the local bus.

The bus controller is responsible for generating 20 bits of address, read and write strobes, bus cycle status information and data (for write operations) information. It is also responsible for reading data from the local bus during a read operation. Synchronous and asynchronous ready input pins are provided to extend a bus cycle beyond the minimum four states (clocks).

The 80C186XL bus controller also generates two control signals ($\overline{\text{DEN}}$ and DT/R) when interfacing to external transceiver chips. This capability allows the addition of transceivers for simple buffering of the multiplexed address/data bus.

During RESET the local bus controller will perform the following action:

- Drive DEN, RD and WR HIGH for one clock cycle, then float them.
- Drive S0-S2 to the inactive state (all HIGH) and then float.
- Drive LOCK HIGH and then float.
- Float AD0-15 (AD0-8), A16-19 (A9-A19), BHE (RFSH), DT/R.
- Drive ALE LOW
- Drive HLDA LOW.

<u>RD/QSMD</u>, <u>UCS</u>, <u>LCS</u>, <u>MCS0/PEREQ</u>, <u>MCS1/</u> <u>ERROR</u> and <u>TEST/BUSY</u> pins have internal pullup devices which are active while <u>RES</u> is applied. Excessive loading or grounding certain of these pins causes the 80C186XL to enter an alternative mode of operation:

- RD/QSMD low results in Queue Status Mode.
- UCS and LCS low results in ONCE Mode.
- TEST/BUSY low (and high later) results in Enhanced Mode.

80C186XL PERIPHERAL ARCHITECTURE

All the 80C186XL integrated peripherals are controlled by 16-bit registers contained within an internal 256-byte control block. The control block may be mapped into either memory or I/O space. Internal logic will recognize control block addresses and respond to bus cycles. An offset map of the 256-byte control register block is shown in Figure 3.

Chip-Select/Ready Generation Logic

The 80C186XL contains logic which provides programmable chip-select generation for both memories and peripherals. In addition, it can be programmed to provide READY (or WAIT state) generation. It can also provide latched address bits A1 and A2. The chip-select lines are active for all memory and I/O cycles in their programmed areas, whether they be generated by the CPU or by the integrated DMA unit.

The 80C186XL provides 6 memory chip select outputs for 3 address areas; upper memory, lower memory, and midrange memory. One each is provided for upper memory and lower memory, while four are provided for midrange memory.

	OFFSET
Relocation Register	FEH
DMA Descriptors Channel 1	DAH
	D0H
DMA Descriptors Channel 0	CAH
	СОН
	A8H
Chip-Select Control Registers	
	A0H
	66H
Time 2 Control Registers	60H
	5EH
Time 1 Control Registers	58H
Time 0 Control Registers	56H
	50H
Interrupt Controller Registers	3EH
	20H

Figure 3. Internal Register Map

The 80C186XL provides a chip select, called $\overline{\text{UCS}}$, for the top of memory. The top of memory is usually used as the system memory because after reset the 80C186XL begins executing at memory location FFFF0H.



The 80C186XL provides a chip select for low memory called $\overline{\text{LCS}}$. The bottom of memory contains the interrupt vector table, starting at location 00000H.

The 80C186XL provides four $\overline{\text{MCS}}$ lines which are active within a user-locatable memory block. This block can be located within the 80C186XL 1 Mbyte memory address space exclusive of the areas defined by $\overline{\text{UCS}}$ and $\overline{\text{LCS}}$. Both the base address and size of this memory block are programmable.

The 80C186XL can generate chip selects for up to seven peripheral devices. These chip selects are active for seven contiguous blocks of 128 bytes above a programmable base address. The base address may be located in either memory or I/O space.

The 80C186XL can generate a READY signal internally for each of the memory or peripheral \overline{CS} lines. The number of WAIT states to be inserted for each peripheral or memory is programmable to provide 0–3 wait states for all accesses to the area for which the chip select is active. In addition, the 80C186XL may be programmed to either ignore external READY for each chip-select range individually or to factor external READY with the integrated ready generator.

Upon RESET, the Chip-Select/Ready Logic will perform the following actions:

- · All chip-select outputs will be driven HIGH.
- Upon leaving RESET, the UCS line will be programmed to provide chip selects to a 1K block with the accompanying READY control bits set at 011 to insert 3 wait states in conjunction with external READY (i.e., UMCS resets to FFFBH).
- No other chip select or READY control registers have any predefined values after RESET. They will not become active until the CPU accesses their control registers.

DMA Unit

The 80C186XL DMA controller provides two independent high-speed DMA channels. Data transfers can occur between memory and I/O spaces (e.g., Memory to I/O) or within the same space (e.g., Memory to Memory or I/O to I/O). Data can be transferred either in bytes (8 bits) or in words (16 bits) to or from even or odd addresses.

NOTE:

Only byte transfers are possible on the 80C188XL.

Each DMA channel maintains both a 20-bit source and destination pointer which can be optionally incremented or decremented after each data transfer (by one or two depending on byte or word transfers). Each data transfer consumes 2 bus cycles (a minimum of 8 clocks), one cycle to fetch data and the other to store data.

Timer/Counter Unit

The 80C186XL provides three internal 16-bit programmable timers. Two of these are highly flexible and are connected to four external pins (2 per timer). They can be used to count external events, time external events, generate nonrepetitive waveforms, etc. The third timer is not connected to any external pins, and is useful for real-time coding and time delay applications. In addition, the third timer can be used as a prescaler to the other two, or as a DMA request source.

Interrupt Control Unit

The 80C186XL can receive interrupts from a number of sources, both internal and external. The 80C186XL has 5 external and 2 internal interrupt sources (Timer/Couners and DMA). The internal interrupt controller serves to merge these requests on a priority basis, for individual service by the CPU.

Enhanced Mode Operation

In Compatible Mode the 80C186XL operates with all the features of the NMOS 80186, with the exception of 8087 support (i.e. no math coprocessing is possible in Compatible Mode). Queue-Status information is still available for design purposes other than 8087 support.

All the Enhanced Mode features are completely masked when in Compatible Mode. A write to any of the Enhanced Mode registers will have no effect, while a read will not return any valid data.

In Enhanced Mode, the 80C186XL will operate with Power-Save, DRAM refresh, and numerics coprocessor support (80C186XL only) in addition to all the Compatible Mode features.

If connected to a math coprocessor (80C186XL only), this mode will be invoked automatically. Without an NPX, this mode can be entered by tying the RESET output signal from the 80C186XL to the TEST/BUSY input.

Queue-Status Mode

The queue-status mode is entered by strapping the $\overline{\text{RD}}$ pin low. $\overline{\text{RD}}$ is sampled at RESET and if LOW, the 80C186XL will reconfigure the ALE and $\overline{\text{WR}}$ pins to be QS0 and QS1 respectively. This mode is available on the 80C186XL in both Compatible and Enhanced Modes.

DRAM Refresh Control Unit

The Refresh Control Unit (RCU) automatically generates DRAM refresh bus cycles. The RCU operates only in Enhanced Mode. After a programmable period of time, the RCU generates a memory read request to the BIU. If the address generated during a refresh bus cycle is within the range of a properly programmed chip select, that chip select will be activated when the BIU executes the refresh bus cycle.

Power-Save Control

The 80C186XL, when in Enhanced Mode, can enter a power saving state by internally dividing the processor clock frequency by a programmable factor. This divided frequency is also available at the CLKOUT pin.

All internal logic, including the Refresh Control Unit and the timers, have their clocks slowed down by the division factor. To maintain a real time count or a fixed DRAM refresh rate, these peripherals must be re-programmed when entering and leaving the power-save mode.

Interface for 80C187 Math Coprocessor (80C186XL Only)

In Enhanced Mode, three of the mid-range memory chip selects are redefined according to Table 1 for use with the 80C187. The fourth chip select, MCS2

functions as in compatible mode, and may be programmed for activity with ready logic and wait states accordingly. As in Compatible Mode, $\overline{\text{MCS2}}$ will function for one-fourth a programmed block size.

Table 1. MCS Assignments

Compatible Mode		Enhanced Mode
MCS0	PEREQ	Processor Extension Request
MCS1	ERROR	NPX Error
MCS2	MCS2	Mid-Range Chip Select
MCS3	NPS	Numeric Processor Select

ONCE Test Mode

To facilitate testing and inspection of devices when fixed into a target system, the 80C186XL has a test mode available which allows all pins to be placed in a high-impedance state. ONCE stands for "ON Circuit Emulation". When placed in this mode, the 80C186XL will put all pins in the high-impedance state until RESET.

The ONCE mode is selected by tying the UCS and the LCS LOW during RESET. These pins are sampled on the low-to-high transition of the RES pin. The UCS and the LCS pins have weak internal pullup resistors similar to the RD and TEST/BUSY pins to guarantee ONCE Mode is not entered inadvertently during normal operation. LCS and UCS must be held low at least one clock after RES goes high to guarantee entrance into ONCE Mode.

PACKAGE INFORMATION

This section describes the pin functions, pinout and thermal characteristics for the 80C186XL in the Quad Flat Pack (QFP), Plastic Leaded Chip Carrier (PLCC), Leadless Chip Carrier (LCC) and the Shrink Quad Flat Pack (SQFP). For complete package specifications and information, see the Intel Packaging Outlines and Dimensions Guide (Order Number: 231369).

Pin Descriptions

Each pin or logical set of pins is described in Table 3. There are four columns for each entry in the Pin Description Table. The following sections describe each column.

Column 1: Pin Name

In this column is a mnemonic that describes the pin function. Negation of the signal name (i.e., $\overline{\text{RESIN}}$) implies that the signal is active low.

Column 2: Pin Type

A pin may be either power (P), ground (G), input only (I), output only (O) or input/output (I/O). Please note that some pins have more than one function.

Column 3: Input Type (for I and I/O types only)

These are two different types of input pins on the 80C186XL: asynchronous and synchronous. **Asynchronous** pins require that setup and hold times be met only to *guarantee recognition*. **Synchronous** input pins require that the setup and hold times be met to *guarantee*

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proper operation. Stated simply, missing a setup or hold on an asynchronous pin will result in something minor (i.e., a timer count will be missed) whereas missing a setup or hold on a synchronous pin result in system failure (the system will "lock up").

An input pin may also be edge or level sensitive.

Column 4: Output States (for O and I/O types only)

The state of an output or I/O pin is dependent on the operating mode of the device. There are four modes of operation that are different from normal active mode: Bus Hold, Reset, Idle Mode, Powerdown Mode. This column describes the output pin state in each of these modes.

The legend for interpreting the information in the Pin Descriptions is shown in Table 2.

As an example, please refer to the table entry for AD7:0. The "I/O" signifies that the pins are bidirectional (i.e., have both an input and output function). The "S" indicates that, as an input the signal must be synchronized to CLKOUT for proper operation. The "H(Z)" indicates that these pins will float while the processor is in the Hold Acknowledge state. R(Z) indicates that these pins will float while RESIN is low.

All pins float while the processor is in the ONCE Mode (with the exception of X2).

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Symbol	Description
Р	Power Pin (apply $+ V_{CC}$ voltage)
G	Ground (connect to V _{SS})
I	Input only pin
0	Output only pin
I/O	Input/Output pin
S(E)	Synchronous, edge sensitive
S(L)	Synchronous, level sensitive
A(E)	Asynchronous, edge sensitive
A(L)	Asynchronous, level sensitive
H(1)	Output driven to V _{CC} during bus hold
H(0)	Output driven to V _{SS} during bus hold
H(Z)	Output floats during bus hold
H(Q)	Output remains active during bus hold
H(X)	Output retains current state during bus hold
R(WH)	Output weakly held at V_{CC} during reset
R(1)	Output driven to V _{CC} during reset
R(0)	Output driven to V _{SS} during reset
R(Z)	Output floats during reset
R(Q)	Output remains active during reset
R(X)	Output retains current state during reset

Table 2. Pin Description Nomenclature



Table 3. Pin Descriptions

Pin Name	Pin Type	Input Type	Output States	Pin Description
V _{CC}	Р			System Power: +5 volt power supply.
V _{SS}	G			System Ground.
RESET	0		H(0) R(1)	RESET Output indicates that the CPU is being reset, and can be used as a system reset. It is active HIGH, synchronized with the processor clock, and lasts an integer number of clock periods corresponding to the length of the RES signal. Reset goes inactive 2 clockout periods after RES goes inactive. When tied to the TEST/BUSY pin, RESET forces the processor into enhanced mode. RESET is not floated during bus hold.
X1	I	A(E)		Crystal Inputs X1 and X2 provide external connections for a
X2	0		H(Q) R(Q)	fundamental mode or third overtone parallel resonant crystal for the internal oscillator. X1 can connect to an external clock instead of a crystal. In this case, minimize the capacitance on X2. The input or oscillator frequency is internally divided by two to generate the clock signal (CLKOUT).
CLKOUT	0		H(Q) R(Q)	Clock Output provides the system with a 50% duty cycle waveform. All device pin timings are specified relative to CLKOUT. CLKOUT is active during reset and bus hold.
RES	Ι	A(L)		An active $\overline{\text{RES}}$ causes the processor to immediately terminate its present activity, clear the internal logic, and enter a dormant state. This signal may be asynchronous to the clock. The processor begins fetching instructions approximately 61/2 clock cycles after $\overline{\text{RES}}$ is returned HIGH. For proper initialization, V_{CC} must be within specifications and the clock signal must be stable for more than 4 clocks with $\overline{\text{RES}}$ held LOW. $\overline{\text{RES}}$ is internally synchronized. This input is provided with a Schmitt-trigger to facilitate power-on $\overline{\text{RES}}$ generation via an RC network.
TEST/BUSY (TEST)	Ι	A(E)		The TEST pin is sampled during and after reset to determine whether the processor is to enter Compatible or Enhanced Mode. Enhanced Mode requires TEST to be HIGH on the rising edge of RES and LOW four CLKOUT cycles later. Any other combination will place the processor in Compatible Mode. During power-up, active RES is required to configure TEST/BUSY as an input. A weak internal pullup ensures a HIGH state when the input is not externally driven. TEST—In Compatible Mode this pin is configured to operate as TEST. This pin is examined by the WAIT instruction. If the TEST input is HIGH when WAIT execution begins, instruction execution will suspend. TEST will be resampled every five clocks until it goes LOW, at which time execution will resume. If interrupts are enabled while the processor is waiting for TEST, interrupts will be serviced. BUSY (80C186XL Only)—In Enhanced Mode, this pin is configured to operate as BUSY. The BUSY input is used to notify the 80C186XL of Math Coprocessor activity. Floating point instructions executing in the 80C186XL sample the BUSY pin to determine when the Math Coprocessor is ready to accept a new command. BUSY is active HIGH.

NOTE:

Pin Name	Pin Type	Input Type	Output States	Pin Description
TMR IN 0 TMR IN 1	I	A(L) A(E)		Timer Inputs are used either as clock or control signals, depending upon the programmed timer mode. These inputs are active HIGH (or LOW-to-HIGH transitions are counted) and internally synchronized. Timer Inputs must be tied HIGH when not being used as clock or retrigger inputs.
TMR OUT 0 TMR OUT 1	0		H(Q) R(1)	Timer outputs are used to provide single pulse or continuous waveform generation, depending upon the timer mode selected. These outputs are not floated during a bus hold.
DRQ0 DRQ1	I	A(L)		DMA Request is asserted HIGH by an external device when it is ready for DMA Channel 0 or 1 to perform a transfer. These signals are level-triggered and internally synchronized.
NMI	I	A(E)		The Non-Maskable Interrupt input causes a Type 2 interrupt. An NMI transition from LOW to HIGH is latched and synchronized internally, and initiates the interrupt at the next instruction boundary. NMI must be asserted for at least one CLKOUT period. The Non- Maskable Interrupt cannot be avoided by programming.
INT0 INT1/SELECT	I	A(E) A(L)		Maskable Interrupt Requests can be requested by activating one of these pins. When configured as inputs,
INT2/INTA0 INT3/INTA1/IRQ	1/0	A(E) A(L)	H(1) R(Z)	these pins are active HIGH. Interrupt Requests are synchronized internally. INT2 and INT3 may be configured to provide active-LOW interrupt- acknowledge output signals. All interrupt inputs may be configured to be either edge- or level-triggered. To ensure recognition, all interrupt requests must remain active until the interrupt is acknowledged. When Slave Mode is selected, the function of these pins changes (see Interrupt Controller section of this data sheet).
A19/S6 A18/S5 A17/S4	0		H(Z) R(Z)	Address Bus Outputs and Bus Cycle Status (3–6) indicate the four most significant address bits during T ₁ . These signals are active HIGH.
A16/S3 (A8-A15)				During T_2 , T_3 , T_W and T_4 , the S6 pin is LOW to indicate a CPU-initiated bus cycle or HIGH to indicate a DMA- initiated or refresh bus cycle. During the same T-states, S3, S4 and S5 are always LOW. On the 80C188XL, A15–A8 provide valid address information for the entire bus cycle.
AD0-AD15 (AD0-AD7)	1/0	S(L)	H(Z) R(Z)	Address/Data Bus signals constitute the time multiplexed memory or I/O address (T_1) and data (T_2 , T_3 , T_W and T_4) bus. The bus is active HIGH. For the 80C186XL, A_0 is analogous to BHE for the lower byte of the data bus, pins D_7 through D_0 . It is LOW during T_1 when a byte is to be transferred onto the lower portion of the bus in memory or I/O operations.

Table 3. Pin Descriptions (Continued)

NOTE:



Pin Name	Pin Type	Input Type	Output States			Pin Description	
BHE (RFSH)	0		H(Z) R(Z)	The \overline{BHE} (Bus High Enable) signal is analogous to A0 in that it is used to enable data on to the most significant half of the data bus, pins D15–D8. BHE will be LOW during T ₁ when the upper byte is transferred and will remain LOW through T ₃ and T _W . BHE does not need to be latched. On the 80C188XL, RFSH is asserted LOW to indicate a refresh bus cycle. In Enhanced Mode, BHE (RFSH) will also be used to signify DRAM refresh cycles. A refresh cycle is indicated by both BHE (RFSH) and A0 being HIGH.			
						80C186XL BHE and A0 Encodings	
				BHE Value	A0 Value	Function	
				0 0	0 1	Word Transfer Byte Transfer on upper half of data bus (D15–D8)	
				1	0	Byte Transfer on lower half of data bus (D ₇ –D ₀) Refresh	
ALE/QS0	0		H(0) R(0)	Address Latch Enable/Queue Status 0 is provided by the processor to latch the address. ALE is active HIGH, with addresses guaranteed valid on the trailing edge.			
WR/QS1	0		H(Z) R(Z)	Write Strobe/Queue Status 1 indicates that the data on the bus is to be written into a memory or an I/O device. It is active LOW. When the processor is in Queue Status Mode, the ALE/QS0 and $\overline{WR}/QS1$ pins provide information about processor/instruction queue interaction.			
				QS1	QS0	Queue Operation	
				0 0 1 1	0 1 1 0	No queue operation First opcode byte fetched from the queue Subsequent byte fetched from the queue Empty the queue	
RD/QSMD	0		H(Z) R(1)	Read Strobe is an active LOW signal which indicates that the processor is performing a memory or I/O read cycle. It is guaranteed not to go LOW before the A/D bus is floated. An internal pull-up ensures that RD/QSMD is HIGH during RESET. Following RESET the pin is sampled to determine whether the processor is to provide ALE, RD, and WR, or queue status information. To enable Queue Status Mode, RD must be connected to GND.			
ARDY	I	A(L) S(L)		Asynchronous Ready informs the processor that the addressed memory space or I/O device will complete a data transfer. The ARDY pin accepts a rising edge that is asynchronous to CLKOUT and is active HIGH. The falling edge of ARDY must be synchronized to the processor clock. Connecting ARDY HIGH will always assert the ready condition to the CPU. If this line is unused, it should be tied LOW to yield control to the SRDY pin.			

NOTE:

Pin Name	Pin Type	Input Type	Output States				Pin Description	
SRDY	I	S(L)	_	Synchronous Ready informs the processor that the addressed memory space or I/O device will complete a data transfer. The SRDY pin accepts an active-HIGH input synchronized to CLKOUT. The use of SRDY allows a relaxed system timing over ARDY. This is accomplished by elimination of the one-half clock cycle required to internally synchonize the ARDY input signal. Connecting SRDY high will always assert the ready condition to the CPU. If this line is unused, it should be tied LOW to yield control to the ARDY pin.				
LOCK	0		H(Z) R(Z)	LOCK output indicates that other system bus masters are not to gain control of the system bus. LOCK is active LOW. The LOCK signal is requested by the LOCK prefix instruction and is activated at the beginning of the first data cycle associated with the instruction immediately following the LOCK prefix. It remains active until the completion of that instruction. No instruction prefetching will occur while LOCK is asserted.				
<u>S0</u> <u>S1</u>	0	_	H(Z) R(1)		cycle s matior		SO-S2 are encoded to provide bus-transaction	
S2							Bus Cycle Status Information	
				S2	<u>S1</u>	<u>S0</u>	Bus Cycle Initiated	
				0	0	0	Interrupt Acknowledge	
				0	0	1	Read I/O	
				0	1	0 1	Write I/O Halt	
				1	0	0	Instruction Fetch	
				1	Ő	1	Read Data from Memory	
				1	1	0	Write Data to Memory	
				1	1	1	Passive (no bus cycle)	
					nay be ator.	used a	as a logical M/I \overline{O} indicator, and $\overline{S1}$ as a DT/ \overline{R}	
HOLD	1	A(L)	_				hat another bus master is requesting the local bus.	
HLDA	0	_	H(1) R(0)	The HOLD inducates that allother bus master is requesting the local bus. The HOLD input is active HIGH. The processor generates HLDA (HIGH) in response to a HOLD request. Simultaneous with the issuance of HLDA, the processor will float the local bus and control lines. After HOLD is detected as being LOW, the processor will lower HLDA. When the processor needs to run another bus cycle, it will again drive the local bus and control lines. In Enhanced Mode, HLDA will go low when a DRAM refresh cycle is pending in the processor and an external bus master has control of the bus. It will be up to the external master to relinquish the bus by lowering HOLD so that the processor may execute the refresh cycle.				

Table 3. Pin Descriptions (Continued)

NOTE:



Table 3. Pin Descriptions (Continued)

Pin Name	Pin Type	Input Type	Output States	Pin Description
UCS	1/0	A(L)	H(1) R(WH)	Upper Memory Chip Select is an active LOW output whenever a memory reference is made to the defined upper portion (1K-256K block) of memory. The address range activating UCS is software programmable. UCS and LCS are sampled upon the rising edge of RES. If both pins are held low, the processor will enter ONCE Mode. In ONCE Mode all pins assume a high impedance state and remain so until a subsequent RESET. UCS has a weak internal pullup that is active during RESET to ensure that the processor does not enter ONCE Mode inadvertently.
LCS	I/O	A(L)	H(1) R(WH)	Lower Memory Chip Select is active LOW whenever a memory reference is made to the defined lower portion (1K–256K) of memory. The address range activating LCS is software programmable.
				UCS and LCS are sampled upon the rising edge of RES. If both pins are held low, the processor will enter ONCE Mode. In ONCE Mode all pins assume a high impedance state and remain so until a subsequent RESET. LCS has a weak internal pullup that is active only during RESET to ensure that the processor does not enter ONCE mode inadvertently.
MCS0/PEREQ MCS1/ERROR	I/O	A(L)	H(1) R(WH)	Mid-Range Memory Chip Select signals are active LOW when a memory reference is made to the defined mid-
MCS2 MCS3/NPS	0		H(1) R(1)	range portion of memory (8K–512K). The address ranges activating MCS0–3 are software programmable. On the 80C186XL, in Enhanced Mode, MCS0 becomes a PEREQ input (Processor Extension Request). When connected to the Math Coprocessor, this input is used to signal the 80C186XL when to make numeric data transfers to and from the coprocessor. MCS3 becomes NPS (Numeric Processor Select) which may only be activated by communication to the 80C187. MCS1 becomes ERROR in Enhanced Mode and is used to signal numerics coprocessor errors.
PCS0 PCS1 PCS2 PCS3 PCS4	0		H(1) R(1)	Peripheral Chip Select signals 0–4 are active LOW when a reference is made to the defined peripheral area (64 Kbyte I/O or 1 MByte memory space). The address ranges activating PCS0–4 are software programmable.
PCS5/A1	0		H(1)/H(X) R(1)	Peripheral Chip Select 5 or Latched A1 may be programmed to provide a sixth peripheral chip select, or to provide an internally latched A1 signal. The address range activating PCS5 is software-programmable. PCS5/A1 does not float during bus HOLD. When programmed to provide latched A1, this pin will retain the previously latched value during HOLD.

80C186XL/80C188XL

Pin Name	Pin Type	Input Type	Output States	Pin Description
PCS6/A2	0		H(1)/H(X) R(1)	Peripheral Chip Select 6 or Latched A2 may be programmed to provide a seventh peripheral chip select, or to provide an internally latched A2 signal. The address range activating PCS6 is software-programmable. PCS6/A2 does not float during bus HOLD. When programmed to provide latched A2, this pin will retain the previously latched value during HOLD.
DT/R	0	_	H(Z) R(Z)	Data Transmit/Receive controls the direction of data flow through an external data bus transceiver. When LOW, data is transferred to the procesor. When HIGH the processor places write data on the data bus.
DEN	0	_	H(Z) R(1,Z)	Data Enable is provided as a data bus transceiver output enable. DEN is active LOW during each memory and I/O access (including 80C187 access). DEN is HIGH whenever DT/R changes state. During RESET, DEN is driven HIGH for one clock, then floated.
N.C.	_	_	—	Not connected. To maintain compatibility with future products, do not connect to these pins.

Table 3. Pin Descriptions (Continued)



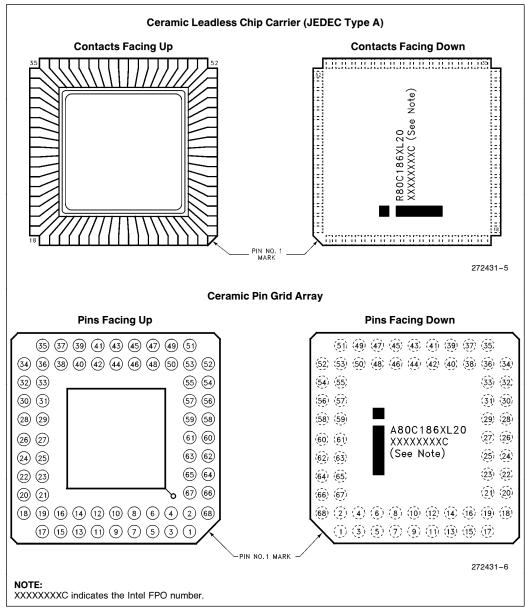


Figure 4. 80C186XL/80C188XL Pinout Diagrams

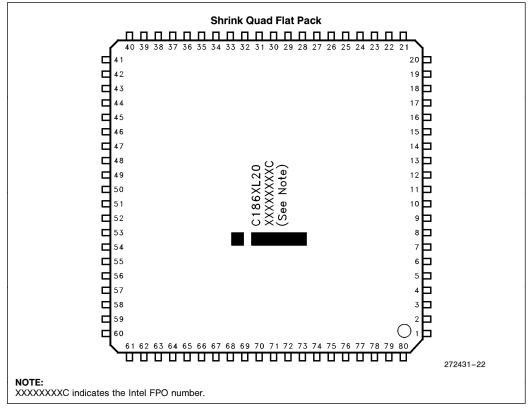


Figure 4. 80C186XL/80C188XL Pinout Diagrams (Continued)

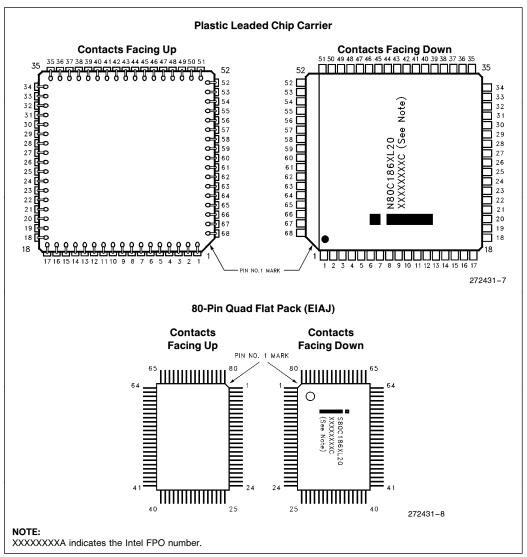


Figure 4. 80C186XL/80C288XL Pinout Diagrams (Continued)

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AD Bus		Bus Control		Processor Control		I/O	
AD0	17	ALE/QS0	61	RES	24	UCS	34
AD1	15	BHE (RFSH)	64	RESET	57	LCS	33
AD2	13	SO	52	X1	59		
AD3	11	<u>S1</u>	53	X2	58	MCS0/PEREQ	38
AD4	8	S2	54	CLKOUT	56	MCS1/ERROR	37
AD5	6	RD/QSMD	62	TEST/BUSY	47	MCS2	36
AD6	4	WR/QS1	63	NMI	46	MCS3/NPS	35
AD7	2	ARDY	55	INT0	45		
AD8 (A8)	16	SRDY	49	INT1/SELECT	44	PCS0	25
AD9 (A9)	14	DEN	39	INT2/INTA0	42	PCS1	27
AD10 (A10)	12	DT/R	40	INT3/INTA1	41	PCS2	28
AD11 (A11)	10	LOCK	48			PCS3	29
AD12 (A12)	7	HOLD	50	Power and Gro	hand	PCS4	30
AD13 (A13)	5	HLDA	51	Power and Gro		PCS5/A1	31
AD14 (A14)	3			V _{CC}	9	PCS6/A2	32
AD15 (A15)	1			V _{CC}	43		
A16/S3	68			V _{SS}	26	TMR IN 0	20
A17/S4	67			V _{SS}	60	TMR IN 1	21
A18/S5	66					TMR OUT 0	22
A19/S6	65					TMR OUT 1	23
						DRQ0	18
						DRQ1	19

Table 4. LCC/PLCC Pin Functions with Location

NOTE:

Pin names in parentheses apply to the 80C188XL.

Table 5. LCC/PGA/PLCC Pin Locations with Pin Names

1	AD15 (A15)	18	DRQ0	35	MCS3/NPS] [52	<u>S0</u>
2	AD7	19	DRQ1	36	MCS2		53	<u>S1</u>
3	AD14 (A14)	20	TMR IN 0	37	MCS1/ERROR		54	S2
4	AD6	21	TMR IN 1	38	MCS0/PEREQ		55	ARDY
5	AD13 (A13)	22	TMR OUT 0	39	DEN		56	CLKOUT
6	AD5	23	TMR OUT 1	40	DT/R		57	RESET
7	AD12 (A12)	24	RES	41	INT3/INTA1		58	X2
8	AD4	25	PCS0	42	INT2/INTA0		59	X1
9	V _{CC}	26	V _{SS}	43	V _{CC}		60	V _{SS}
10	AD11 (A11)	27	PCS1	44	INT1/SELECT		61	ALE/QS0
11	AD3	28	PCS2	45	INT0		62	RD/QSMD
12	AD10 (A10)	29	PCS3	46	NMI		63	WR/QS1
13	AD2	30	PCS4	47	TEST/BUSY		64	BHE (RFSH)
14	AD9 (A9)	31	PCS5/A1	48	LOCK		65	A19/S2
15	AD1	32	PCS6/A2	49	SRDY		66	A18/S3
16	AD8 (A8)	33	LCS	50	HOLD		67	A17/S4
17	AD0	34	UCS	51	HLDA		68	A16/S3

NOTE:



AD Bus						
AD0	64					
AD1	66					
AD2	68					
AD3	70					
AD4	74					
AD5	76					
AD6	78					
AD7	80					
AD8 (A8)	65					
AD9 (A9)	67					
AD10 (A10)	69					
AD11 (A11)	71					
AD12 (A12)	75					
AD13 (A13)	77					
AD14 (A14)	79					
AD15 (A15)	1					
A16/S3	3					
A17/S4	4					
A18/S5	5					
A19/S6	6					

	Bus Control	
	ALE/QS0	10
	BHE (RFSH)	7
	SO	23
	<u>S1</u>	22
	<u>S2</u>	21
	RD/QSMD	9
	WR/QS1	8
	ARDY	20
	SRDY	27
	DEN	38
	DT/R	37
	LOCK	28
	HOLD	26
	HLDA	25
	ſ	
	No Connectio	n
	N.C.	2
	N.C.	11
	N.C.	14
-	N.C.	15
	N.C.	24
	N.C.	43
	N.C.	44
	N.C.	62
	N.C.	63

Table 6. QFP	Pin Fu	nc	tions with Locatio	n				
Bus Control			Processor Control			I/O		
LE/QS0	10		RES	55		UCS	45	
HE (RFSH)	7		RESET	18		LCS	46	
ō	23		X1	16				
1	22		X2	17		MCS0/PEREQ	39	
2	21		CLKOUT	19		MCS1/ERROR	40	
D/QSMD	9		TEST/BUSY	29		MCS2	41	
/R/QS1	8		NMI	30		MCS3/NPS	42	
RDY	20		INT0	31				
RDY	27		INT1/SELECT	32		PCS0	54	
EN	38		INT2/INTA0	35		PCS1	52	
T/R	37		INT3/INTA1	36		PCS2	51	
OCK	28					PCS3	50	
OLD	26		Power and Gro	und		PCS4	49	
LDA	25		Power and Gro	una		PCS5/A1	48	
			V _{CC}	33		PCS6/A2	47	
No Connectio	n		V _{CC}	34				
NO CONNECTIO			V _{CC}	72		TMR IN 0	59	
.C.	2		V _{CC}	73		TMR IN 1	58	
.C.	11		V _{SS}	12		TMR OUT 0	57	
.C.	14		V _{SS}	13		TMR OUT 1	56	
.C.	15		V _{SS}	53				
.C.	24					DRQ0	61	
.C.	43					DRQ1	60	
.C.	44							

NOTE:

Pin names in parentheses apply to the 80C188XL.

Table 7. QFP Pin Locations with Pin Names

					11000		
1	AD15 (A15)	21	<u>S2</u>	41	MCS2	61	DRQ0
2	N.C.	22	<u>S1</u>	42	MCS3/NPS	62	N.C.
3	A16/S3	23	SO	43	N.C.	63	N.C.
4	A17/S4	24	N.C.	44	N.C.	64	AD0
5	A18/S5	25	HLDA	45	UCS	65	AD8 (A8)
6	A19/S6	26	HOLD	46	LCS	66	AD1
7	BHE/(RFSH)	27	SRDY	47	PCS6/A2	67	AD9 (A9)
8	WR/QS1	28	LOCK	48	PCS5/A1	68	AD2
9	RD/QSMD	29	TEST/BUSY	49	PCS4	69	AD10 (A10)
10	ALE/QS0	30	NMI	50	PCS3	70	AD3
11	N.C.	31	INT0	51	PCS2	71	AD11 (A11)
12	V _{SS}	32	INT1/SELECT	52	PCS1	72	V _{CC}
13	V _{SS}	33	V _{CC}	53	V _{SS}	73	V _{CC}
14	N.C.	34	V _{CC}	54	PCS0	74	AD4
15	N.C.	35	INT2/INTA0	55	RES	75	AD12 (A12)
16	X1	36	INT3/INTA1	56	TMR OUT 1	76	AD5
17	X2	37	DT/R	57	TMR OUT 0	77	AD13 (A13)
18	RESET	38	DEN	58	TMR IN 1	78	AD6
19	CLKOUT	39	MCS0/PEREQ	59	TMR IN 0	79	AD14 (A14)
20	ARDY	40	MCS1/ERROR	60	DRQ1	80	AD7

NOTE:

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AD Bus	AD Bus		I	Processor Cor	ntrol	I/O	
AD0	1	ALE/QS0	29	RES	73	UCS	62
AD1	3	BHE (RFSH)	26	RESET	34	LCS	63
AD2	6	SO	40	X1	32		
AD3	8	S1	39	X2	33	MCS0/PEREQ	57
AD4	12	S2	38	CLKOUT	36	MCS1/ERROR	58
AD5	14	RD/QSMD	28	TEST/BUSY	46	MCS2	59
AD6	16	WR/QS1	27	NMI	47	MCS3/NPS	60
AD7	18	ARDY	37	INT0	48		
AD8 (A8)	2	SRDY	44	INT1/SELECT	49	PCS0	71
AD9 (A9)	5	DEN	56	INT2/INTA0	52	PCS1	69
AD10 (A10)	7	DT/R	54	INT3/INTA1	53	PCS2	68
AD11 (A11)	9	LOCK	45			PCS3	67
AD12 (A12)	13	HOLD	43	Power and Gro	- In al	PCS4	66
AD13 (A13)	15	HLDA	42	Power and Gro	una	PCS5/A1	65
AD14 (A14)	17			V _{CC}	10	PCS6/A2	64
AD15 (A15)	19	No Connection	••	V _{CC}	11		
A16/S3	21			V _{CC}	20	TMR IN 0	77
A17/S4	22	N.C.	4	V _{CC}	50	TMR IN 1	76
A18/S5	23	N.C.	25	V _{CC}	51	TMR OUT 0	75
A19/S6	24	N.C.	35	V _{CC}	61	TMR OUT 1	74
		N.C.	55	V _{SS}	30		
		N.C.	72	V _{SS}	31	DRQ0	79
				V _{SS}	41	DRQ1	78
				V _{SS}	70		
				V _{SS}	80		

Table 8. SQFP Pin Functions with Location

NOTE: Pin names in parentheses apply to the 80C188XL.

Table 9. SQFP Pin Locations with Pin Names

1	AD0	21	A16/S3	41	V _{SS}	61	V _{CC}
2	AD8 (A8)	22	A17/S4	42	HLDA	62	UCS
3	AD1	23	A18/S5	43	HOLD	63	LCS
4	N.C.	24	A19/S6	44	SRDY	64	PCS6/A2
5	AD9 (A9)	25	N.C.	45	LOCK	65	PCS5/A1
6	AD2	26	BHE (RFSH)	46	TEST/BUSY	66	PCS4
7	AD10 (A10)	27	WR/QS1	47	NMI	67	PCS3
8	AD3	28	RD/QSMD	48	INT0	68	PCS2
9	AD11 (A11)	29	ALE/QS0	49	INT1/SELECT	69	PCS1
10	V _{CC}	30	V _{SS}	50	V _{CC}	70	V _{SS}
11	V _{CC}	31	V _{SS}	51	V _{CC}	71	PCS0
12	AD4	32	X1	52	INT2/INTA0	72	N.C.
13	AD12 (A12)	33	X2	53	INT3/INTA1	73	RES
14	AD5	34	RESET	54	DT/R	74	TMR OUT 1
15	AD13 (A13)	35	N.C.	55	N.C.	75	TMR OUT 0
16	AD6	36	CLKOUT	56	DEN	76	TMR IN 1
17	AD14 (A14)	37	ARDY	57	MCS0/PEREQ	77	TMR IN 0
18	AD7	38	S2	58	MCS1/ERROR	78	DRQ1
19	AD15 (A15)	39	S1	59	MCS2	79	DRQ0
20	V _{CC}	40	SO	60	MCS3/NPS	80	V _{SS}

NOTE:



ELECTRICAL SPECIFICATIONS

Absolute Maximum Ratings*

Ambient Temperature under Bias $\dots 0^{\circ}C$ to $+70^{\circ}C$
Storage Temperature $\dots -65^{\circ}C$ to $+150^{\circ}C$
Voltage on Any Pin with
Respect to Ground $\dots \dots \dots$

NOTICE: This data sheet contains preliminary information on new products in production. The specifications are subject to change without notice. Verify with your local Intel Sales office that you have the latest data sheet before finalizing a design.

*WARNING: Stressing the device beyond the "Absolute Maximum Ratings" may cause permanent damage. These are stress ratings only. Operation beyond the "Operating Conditions" is not recommended and extended exposure beyond the "Operating Conditions" may affect device reliability.

NOTICE: The specifications are subject to change without notice.

Symbol	Parameter	Min	Max	Units	Test Conditions
V _{IL}	Input Low Voltage (Except X1)	-0.5	$0.2 V_{CC} - 0.3$	V	
V _{IL1}	Clock Input Low Voltage (X1)	-0.5	0.6	V	
VIH	Input High Voltage (All except X1 and RES)	0.2 V _{CC} + 0.9	V _{CC} + 0.5	V	
V _{IH1}	Input High Voltage (RES)	3.0	V _{CC} + 0.5	V	
V _{IH2}	Clock Input High Voltage (X1)	3.9	V _{CC} + 0.5	V	
V _{OL}	Output Low Voltage		0.45	V	$I_{OL} = 2.5 \text{ mA} (S0, 1, 2)$ $I_{OL} = 2.0 \text{ mA} (others)$
V _{OH}	Output High Voltage	2.4	V _{CC}	V	$I_{OH} = -2.4 \text{ mA} @ 2.4 \text{V}^{(4)}$
		$V_{CC} - 0.5$	V _{CC}	V	$I_{OH}=-200\;\mu A @ V_{CC} - 0.5^{(4)}$
ICC	Power Supply Current		100	mA	@ 25 MHz, 0°C V _{CC} = 5.5V ⁽³⁾
			90	mA	@ 20 MHz, 0°C V _{CC} = 5.5V(3)
			62.5	mA	@ 12 MHz, 0°C V _{CC} = 5.5V (3)
			100	μΑ	@ DC 0°C V _{CC} = 5.5V
ILI	Input Leakage Current		±10	μΑ	@ 0.5 MHz, 0.45V \leq V_{IN} \leq V_{CC}
ILO	Output Leakage Current		±10	μΑ	@ 0.5 MHz, 0.45V \leq V _{OUT} \leq V _{CC} ⁽¹⁾
V _{CLO}	Clock Output Low		0.45	V	$I_{CLO} = 4.0 \text{ mA}$

DC SPECIFICATIONS $T_A = 0^{\circ}C \text{ to } + 70^{\circ}C, V_{CC} = 5V \pm 10\%$

Symbol	Parameter	Min	Max	Units	Test Conditions
V _{CHO}	Clock Output High	$V_{CC}-0.5$		V	$I_{CHO} = -500 \ \mu A$
C _{IN}	Input Capacitance		10	pF	@ 1 MHz ⁽²⁾
C _{IO}	Output or I/O Capacitance		20	pF	@ 1 MHz ⁽²⁾

DC SPECIFICATIONS (Continued) $T_A = 0^{\circ}C$ to $+70^{\circ}C$, $V_{CC} = 5V \pm 10\%$

NOTES:

1. Pins being floated during HOLD or by invoking the ONCE Mode.

2. Characterization conditions are a) Frequency = 1 MHz; b) Unmeasured pins at GND; c) VIN at + 5.0V or 0.45V. This parameter is not tested.

3. Current is measured with the device in RESET with X1 and X2 driven and all other non-power pins open. 4. RD/QSMD, UCS, LCS, MCS0/PEREQ, MCS1/ERROR and TEST/BUSY pins have internal pullup devices. Loading some of these pins above $I_{OH} = -200 \ \mu$ A can cause the processor to go into alternative modes of operation. See the section on Local Bus Controller and Reset for details.

Power Supply Current

Current is linearly proportional to clock frequency and is measured with the device in RESET with X1 and X2 driven and all other non-power pins open.

Maximum current is given by I_{CC} = 5 mA \times freq. (MHz) + I_{QL} .

 I_{QL} is the quiescent leakage current when the clock is static. I_{QL} is typically less than 100 μ A.

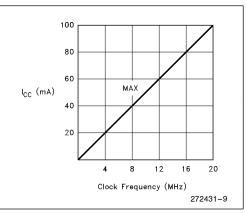


Figure 5. I_{CC} vs Frequency



AC SPECIFICATIONS

MAJOR CYCLE TIMINGS (READ CYCLE)

T_A = 0°C to + 70°C, V_{CC} = 5V ± 10% All timings are measured at 1.5V and 50 pF loading on CLKOUT unless otherwise noted. All output test conditions are with C_L = 50 pF. For AC tests, input V_{IL} = 0.45V and V_{IH} = 2.4V except at X1 where V_{IH} = V_{CC} - 0.5V.

				Values					
Symbol	Parameter	80C186XL	.25	80C186XL	.20	80C186XL	.12	Unit	Test Conditions
		Min	Мах	Min	Мах	Min	Мах		••••••
80C186	XL GENERAL TIMING REQU	JIREMENTS	(List	ed More Tha	n On	ce)			
T _{DVCL}	Data in Setup (A/D)	8		10		15		ns	
T _{CLDX}	Data in Hold (A/D)	3		3		3		ns	
80C1862	XL GENERAL TIMING RESP	ONSES (List	ted N	lore Than On	ice)				
T _{CHSV}	Status Active Delay	3	20	3	25	3	35	ns	
T _{CLSH}	Status Inactive Delay	3	20	3	25	3	35	ns	
T _{CLAV}	Address Valid Delay	3	20	3	27	3	36	ns	
T _{CLAX}	Address Hold	0		0		0		ns	
T _{CLDV}	Data Valid Delay	3	20	3	27	3	36	ns	
T _{CHDX}	Status Hold Time	10		10		10		ns	
T _{CHLH}	ALE Active Delay		20		20		25	ns	
T _{LHLL}	ALE Width	T _{CLCL} – 15		T _{CLCL} – 15		T _{CLCL} – 15		ns	
T _{CHLL}	ALE Inactive Delay		20		20		25	ns	
T _{AVLL}	Address Valid to ALE Low	T _{CLCH} – 10		T _{CLCH} – 10		T _{CLCH} – 15		ns	Equal Loading
T _{LLAX}	Address Hold from ALE Inactive	T _{CHCL} – 8		T _{CHCL} – 10		T _{CHCL} – 15		ns	Equal Loading
T _{AVCH}	Address Valid to Clock High	0		0		0		ns	
T _{CLAZ}	Address Float Delay	T _{CLAX}	20	T _{CLAX}	20	T _{CLAX}	25	ns	
T _{CLCSV}	Chip-Select Active Delay	3	20	3	25	3	33	ns	
T _{CXCSX}	Chip-Select Hold from Command Inactive	T _{CLCH} – 10		T _{CLCH} – 10		T _{CLCH} – 10		ns	Equal Loading
T _{CHCSX}	Chip-Select Inactive Delay	3	17	3	20	3	30	ns	
T _{DXDL}	$\overline{\text{DEN}}$ Inactive to $\text{DT}/\overline{\text{R}}$ Low	0		0		0		ns	Equal Loading
T _{CVCTV}	Control Active Delay 1	3	17	3	22	3	37	ns	
T _{CVDEX}	DEN Inactive Delay	3	17	3	22	3	37	ns	
ТСНСТУ	Control Active Delay 2	3	20	3	22	3	37	ns	
T _{CLLV}	LOCK Valid/Invalid Delay	3	17	3	22	3	37	ns	

AC SPECIFICATIONS (Continued)

MAJOR CYCLE TIMINGS (READ CYCLE) (Continued)

 $\begin{array}{l} T_A = 0^\circ C \ to + 70^\circ C, \ V_{CC} = 5V \pm 10\% \\ \mbox{All timings are measured at 1.5V and 50 pF loading on CLKOUT unless otherwise noted.} \\ \mbox{All output test conditions are with } C_L = 50 \ pF. \\ \mbox{For AC tests, input } V_{IL} = 0.45V \ \mbox{and } V_{IH} = 2.4V \ \mbox{except at X1 where } V_{IH} = V_{CC} - 0.5V. \end{array}$

Symbol	Parameter	80C186XL	25	80C186XL	20	80C186XL	12	Unit	Test Conditions
		Min	Max	Min	Мах	Min	Max		
80C186)	L TIMING RESPO	NSES (Read C	ycle)						
T _{AZRL}	Address Float to RD Active	0		0		0		ns	
T _{CLRL}	RD Active Delay	3	20	3	27	3	37	ns	
T _{RLRH}	RD Pulse Width	2T _{CLCL} - 15		2T _{CLCL} - 20		2T _{CLCL} – 25		ns	
T _{CLRH}	RD Inactive Delay	3	20	3	27	3	37	ns	
T _{RHLH}	RD Inactive to ALE High	T _{CLCH} – 14	с.	T _{CLCH} – 14		T _{CLCH} – 14		ns	Equal Loading
T _{RHAV}	RD Inactive to Address Active	T _{CLCL} – 15		T _{CLCL} – 15		T _{CLCL} – 15		ns	Equal Loading



AC SPECIFICATIONS (Continued)

MAJOR CYCLE TIMINGS (WRITE CYCLE)

T_A = 0°C to +70°C, V_{CC} = 5V ±10% All timings are measured at 1.5V and 50 pF loading on CLKOUT unless otherwise noted. All output test conditions are with C_L = 50 pF. For AC tests, input V_{IL} = 0.45V and V_{IH} = 2.4V except at X1 where V_{IH} = V_{CC} - 0.5V.

				Values					
Symbol	Parameter	80C186XL	25	80C186XL	20	80C186XL	12	Unit	Test Conditions
		Min	Max	Min	Мах	Min	Max	1	Conditions
80C186)	L GENERAL TIMING RESPO	ONSES (Liste	d Mo	re Than Once)				
T _{CHSV}	Status Active Delay	3	20	3	25	3	35	ns	
T _{CLSH}	Status Inactive Delay	3	20	3	25	3	35	ns	
T _{CLAV}	Address Valid Delay	3	20	3	27	3	36	ns	
T _{CLAX}	Address Hold	0		0		0		ns	
T _{CLDV}	Data Valid Delay	3	20	3	27	3	36	ns	
T _{CHDX}	Status Hold Time	10		10		10		ns	
T _{CHLH}	ALE Active Delay		20		20		25	ns	
T _{LHLL}	ALE Width	T _{CLCL} – 15		T _{CLCL} – 15		T _{CLCL} – 15		ns	
T _{CHLL}	ALE Inactive Delay		20		20		25	ns	
T _{AVLL}	Address Valid to ALE Low	T _{CLCH} - 10		T _{CLCH} - 10		T _{CLCH} – 15		ns	Equal Loading
T _{LLAX}	Address Hold from ALE Inactive	T _{CHCL} – 10		T _{CHCL} – 10		T _{CHCL} – 15		ns	Equal Loading
T _{AVCH}	Address Valid to Clock High	0		0		0		ns	
T _{CLDOX}	Data Hold Time	3		3		3		ns	
т _{сусту}	Control Active Delay 1	3	20	3	25	3	37	ns	
т _{сустх}	Control Inactive Delay	3	17	3	25	3	37	ns	
T _{CLCSV}	Chip-Select Active Delay	3	20	3	25	3	33	ns	
T _{CXCSX}	Chip-Select Hold from Command Inactive	T _{CLCH} - 10		T _{CLCH} - 10		T _{CLCH} - 10		ns	Equal Loading
T _{CHCSX}	Chip-Select Inactive Delay	3	17	3	20	3	30	ns	
T _{DXDL}	$\overline{\text{DEN}}$ Inactive to $\text{DT}/\overline{\text{R}}$ Low	0		0		0		ns	Equal Loading
T _{CLLV}	LOCK Valid/Invalid Delay	3	17	3	22	3	37	ns	
80C186)	(L TIMING RESPONSES (Wr	ite Cycle)							
T _{WLWH}	WR Pulse Width	2T _{CLCL} – 15		2T _{CLCL} - 20		2T _{CLCL} – 25		ns	
T _{WHLH}	WR Inactive to ALE High	T _{CLCH} – 14		T _{CLCH} – 14		T _{CLCH} – 14		ns	Equal Loading
T _{WHDX}	Data Hold after WR	T _{CLCL} – 10		T _{CLCL} – 15		T _{CLCL} – 20		ns	Equal Loading
T _{WHDEX}	WR Inactive to DEN Inactive	T _{CLCH} - 10		T _{CLCH} – 10		T _{CLCH} - 10		ns	Equal Loading

AC SPECIFICATIONS (Continued)

MAJOR CYCLE TIMINGS (INTERRUPT ACKNOWLEDGE CYCLE)

 $T_A = 0^{\circ}C \text{ to } + 70^{\circ}C, V_{CC} = 5V \pm 10\%$ All timings are measured at 1.5V and 50 pF loading on CLKOUT unless otherwise noted. All output test conditions are with $C_L = 50$ pF. For AC tests, input $V_{IL} = 0.45V$ and $V_{IH} = 2.4V$ except at X1 where $V_{IH} = V_{CC} - 0.5V$.

Symbol	Parameter	80C186XL	.25	80C186XL	.20	80C186XL	.12	Unit	Test Conditions
		Min	Max	Min	Max	Min	Max		
80C186	XL GENERAL TIMING REQU	JIREMENTS	(List	ed More Tha	n On	ce)			
T _{DVCL}	Data in Setup (A/D)	8		10		15		ns	
T _{CLDX}	Data in Hold (A/D)	3		3		3		ns	
80C186	XL GENERAL TIMING RESP	ONSES (List	ed N	lore Than On	ice)				
T _{CHSV}	Status Active Delay	3	20	3	25	3	35	ns	
T _{CLSH}	Status Inactive Delay	3	20	3	25	3	35	ns	
T _{CLAV}	Address Valid Delay	3	20	3	27	3	36	ns	
T _{AVCH}	Address Valid to Clock High	0		0		0		ns	
T _{CLAX}	Address Hold	0		0		0		ns	
T _{CLDV}	Data Valid Delay	3	20	3	27	3	36	ns	
T _{CHDX}	Status Hold Time	10		10		10		ns	
T _{CHLH}	ALE Active Delay		20		20		25	ns	
T _{LHLL}	ALE Width	T _{CLCL} – 15		T _{CLCL} – 15		T _{CLCL} – 15		ns	
T _{CHLL}	ALE Inactive Delay		20		20		25	ns	
T _{AVLL}	Address Valid to ALE Low	T _{CLCH} – 10		T _{CLCH} – 10		T _{CLCH} – 15		ns	Equal Loading
T _{LLAX}	Address Hold to ALE Inactive	T _{CHCL} – 10		T _{CHCL} – 10		T _{CHCL} – 15		ns	Equal Loading
T _{CLAZ}	Address Float Delay	T _{CLAX}	20	T _{CLAX}	20	T _{CLAX}	25	ns	
T _{CVCTV}	Control Active Delay 1	3	17	3	25	3	37	ns	
Тсустх	Control Inactive Delay	3	17	3	25	3	37	ns	
T _{DXDL}	$\overline{\text{DEN}}$ Inactive to $\text{DT}/\overline{\text{R}}$ Low	0		0		0		ns	Equal Loading
Т _{СНСТV}	Control Active Delay 2	3	20	3	22	3	37	ns	
T _{CVDEX}	DEN Inactive Delay (Non-Write Cycles)	3	17	3	22	3	37	ns	
T _{CLLV}	LOCK Valid/Invalid Delay	3	17	3	22	3	37	ns	



AC SPECIFICATIONS (Continued)

SOFTWARE HALT CYCLE TIMINGS

 $\begin{array}{l} T_A = 0^\circ C \ to \ +70^\circ C, \ V_{CC} = 5V \ \pm 10\% \\ \mbox{All timings are measured at 1.5V and 50 pF loading on CLKOUT unless otherwise noted.} \\ \mbox{All output test conditions are with } C_L = 50 \ pF. \\ \mbox{For AC tests, input } V_{IL} = 0.45V \ \mbox{and } V_{IH} = 2.4V \ \mbox{except at X1 where } V_{IH} = V_{CC} - 0.5V. \end{array}$

Symbol	Parameter	80C186XL25		80C186XL20		80C186XL12		Unit	Test Conditions
		Min	Max	Min	Max	Min	Max		Conditionio
80C186	XL GENERAL TIMING REQ	UIREMENTS	i (List	ted More Tha	an On	ce)			
T _{CHSV}	Status Active Delay	3	20	3	25	3	35	ns	
T _{CLSH}	Status Inactive Delay	3	20	3	25	3	35	ns	
T _{CLAV}	Address Valid Delay	3	20	3	27	3	36	ns	
T _{CHLH}	ALE Active Delay		20		20		25	ns	
T _{LHLL}	ALE Width	T _{CLCL} – 15		T _{CLCL} – 15		T _{CLCL} – 15		ns	
T _{CHLL}	ALE Inactive Delay		20		20		25	ns	
T _{DXDL}	DEN Inactive to DT/R Low		0		0		0	ns	Equal Loading
ТСНСТУ	Control Active Delay 2	3	20	3	22	3	37	ns	

AC SPECIFICATIONS (Continued)

CLOCK TIMINGS

 $\begin{array}{l} T_A = 0^\circ C \ to + 70^\circ C, \ V_{CC} = 5V \ \pm 10\% \\ \mbox{All timings are measured at 1.5V and 50 pF loading on CLKOUT unless otherwise noted.} \\ \mbox{All toutput test conditions are with } C_L = 50 \ pF. \\ \mbox{For AC tests, input } V_{IL} = 0.45V \ \mbox{and } V_{IH} = 2.4V \ \mbox{except at X1 where } V_{IH} = V_{CC} - 0.5V. \end{array}$

Symbol	Parameter	80C186XL2	25	80C186XL2	20	80C186XL1	2	Unit	Test Conditions
		Min	Max	Min	Max	Min	Max		Conditions
80C186X	L CLKIN REQUIR	EMENTS ⁽¹⁾							
T _{CKIN}	CLKIN Period	20	8	25	8	40	8	ns	
T _{CLCK}	CLKIN Low Time	8	8	10	ø	16	8	ns	1.5V(2)
тснск	CLKIN High Time	8	8	10	ø	16	8	ns	1.5V ⁽²⁾
T _{CKHL}	CLKIN Fall Time		5		5		5	ns	3.5 to 1.0V
T _{CKLH}	CLKIN Rise Time		5		5		5	ns	1.0 to 3.5V
80C186X		IG							
T _{CICO}	CLKIN to CLKOUT Skew		17		17		21	ns	
T _{CLCL}	CLKOUT Period	40	8	50		80	8	ns	
T _{CLCH}	CLKOUT Low Time	0.5 T _{CLCL} — 5		0.5 T _{CLCL} — 5		0.5 T _{CLCL} — 5		ns	$C_{L} = 100 \text{ pF}^{(3)}$
T _{CHCL}	CLKOUT High Time	0.5 T _{CLCL} — 5	-	0.5 T _{CLCL} — 5		0.5 T _{CLCL} — 5		ns	$C_{L} = 100 \text{ pF}^{(4)}$
T _{CH1CH2}	CLKOUT Rise Time		6		8		10	ns	1.0 to 3.5V
T _{CL2CL1}	CLKOUT Fall Time		6		8		10	ns	3.5 to 1.0V

NOTES:

1. External clock applied to X1 and X2 not connected. 2. T_{CLCK} and T_{CHCK} (CLKIN Low and High times) should not have a duration less than 40% of T_{CKIN} . 3. Tested under worst case conditions: $V_{CC} = 5.5V$. $T_A = 70^{\circ}C$. 4. Tested under worst case conditions: $V_{CC} = 4.5V$. $T_A = 0^{\circ}C$.



AC SPECIFICATIONS (Continued)

READY, PERIPHERAL AND QUEUE STATUS TIMINGS

 $\begin{array}{l} T_A = 0^\circ C \ to \ + 70^\circ C, \ V_{CC} = 5V \ \pm 10\% \\ \mbox{All timings are measured at 1.5V and 50 pF loading on CLKOUT unless otherwise noted.} \\ \mbox{All output test conditions are with } C_L = 50 \ pF. \\ \mbox{For AC tests, input } V_{IL} = 0.45V \ \mbox{and } V_{IH} = 2.4V \ \mbox{except at X1 where } V_{IH} = V_{CC} - 0.5V. \end{array}$

Symbol	Parameter	80C186XL25		80C186XL20		80C186XL12		Unit	Test Conditions
		Min	Max	Min	Max	Min	Max		Contaitionio
80C186X	80C186XL READY AND PERIPHERAL TIMING REQUIREMENTS (Listed More Than On								
T _{SRYCL}	Synchronous Ready (SRDY) Transition Setup Time ⁽¹⁾	8		10		15		ns	
T _{CLSRY}	SRDY Transition Hold Time ⁽¹⁾	8		10		15		ns	
T _{ARYCH}	ARDY Resolution Transition Setup Time ⁽²⁾	8		10		15		ns	
T _{CLARX}	ARDY Active Hold Time ⁽¹⁾	8		10		15		ns	
TARYCHL	ARDY Inactive Holding Time	8		10		15		ns	
TARYLCL	Asynchronous Ready (ARDY) Setup Time ⁽¹⁾	10		15		25		ns	
T _{INVCH}	INTx, NMI, TEST/BUSY, TMR IN Setup Time ⁽²⁾	8		10		15		ns	
TINVCL	DRQ0, DRQ1 Setup Time ⁽²⁾	8		10		15		ns	
80C186X	L PERIPHERAL AND QUEUE S	RESPO	NSES						
T _{CLTMV}	Timer Output Delay		17		22		33	ns	
T _{CHQSV}	Queue Status Delay		22		27		32	ns	

NOTES:

To guarantee proper operation.
 To guarantee recognition at clock edge.

AC SPECIFICATIONS (Continued)

RESET AND HOLD/HLDA TIMINGS

T_A = 0°C to +70°C, V_{CC} = 5V ±10% All timings are measured at 1.5V and 50 pF loading on CLKOUT unless otherwise noted. All output test conditions are with C_L = 50 pF. For AC tests, input V_{IL} = 0.45V and V_{IH} = 2.4V except at X1 where V_{IH} = V_{CC} - 0.5V.

Symbol	Parameter	80C186XL25		80C18	6XL20	80C18	6XL12	Unit	Test Conditions		
		Min	Мах	Min	Мах	Min	Мах		Conditions		
80C186X	0C186XL RESET AND HOLD/HLDA TIMING REQUIREMENTS										
T _{RESIN}	RES Setup	15		15		15		ns			
T _{HVCL}	HOLD Setup ⁽¹⁾	8		10		15		ns			
80C186X	(L GENERAL TIMING RESPO	NSES (L	isted M	ore Thai	n Once)						
T _{CLAZ}	Address Float Delay	T _{CLAX}	20	T _{CLAX}	20	T _{CLAX}	25	ns			
T _{CLAV}	Address Valid Delay	3	20	3	22	3	36	ns			
80C186X	(L RESET AND HOLD/HLDA	TIMING	RESPO	NSES							
T _{CLRO}	Reset Delay		17		22		33	ns			
T _{CLHAV}	HLDA Valid Delay	3	17	3	22	3	33	ns			
T _{CHCZ}	Command Lines Float Delay		22		25		33	ns			
T _{CHCV}	Command Lines Valid Delay (after Float)		20		26		36	ns			

NOTE:

1. To guarantee recognition at next clock.



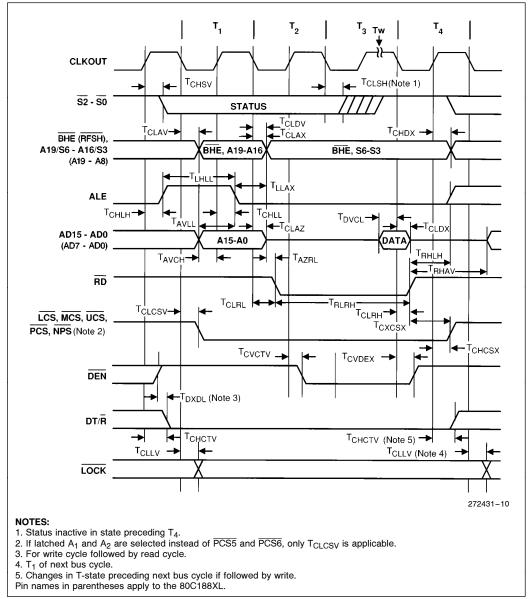


Figure 6. Read Cycle Waveforms

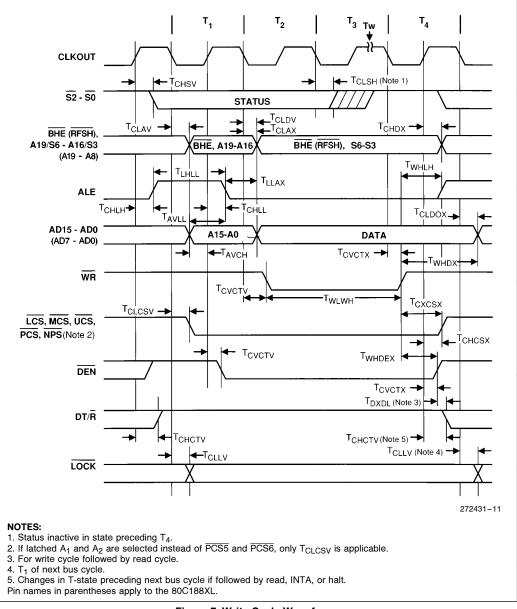


Figure 7. Write Cycle Waveforms



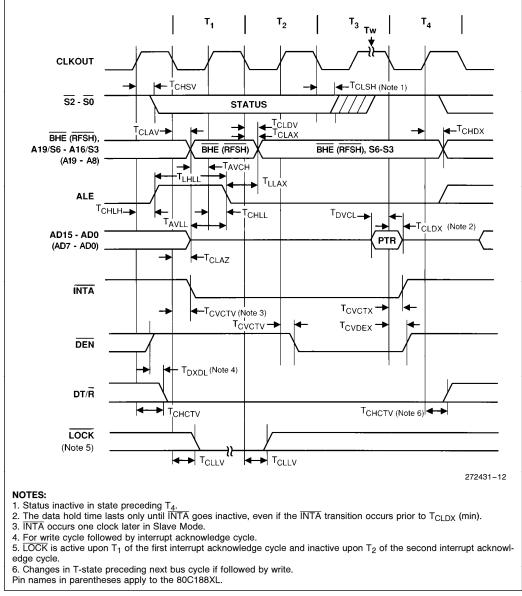


Figure 8. Interrupt Acknowledge Cycle Waveforms

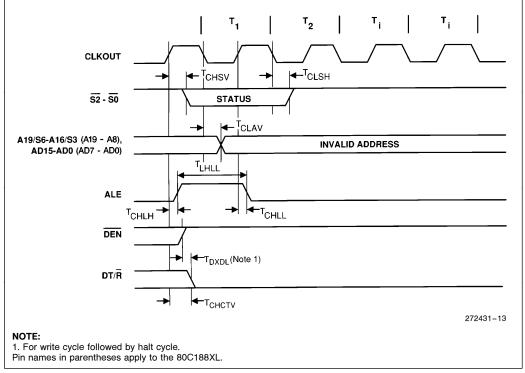
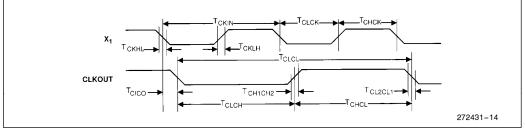
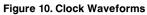


Figure 9. Software Halt Cycle Waveforms



WAVEFORMS





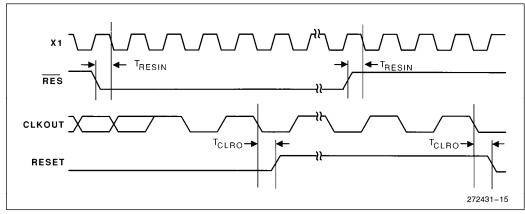


Figure 11. Reset Waveforms

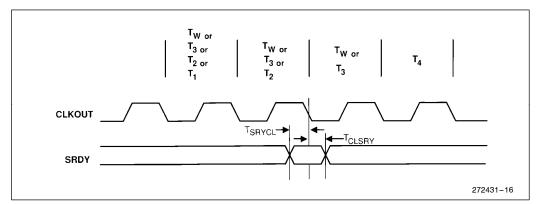


Figure 12. Synchronous Ready (SRDY) Waveforms

AC CHARACTERISTICS

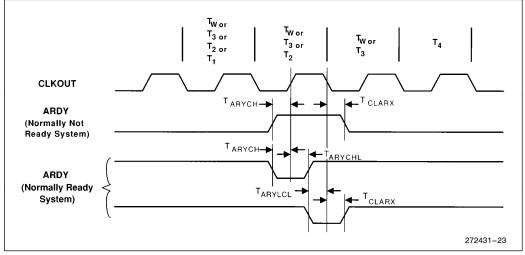


Figure 13. Asynchronous Ready (ARDY) Waveforms

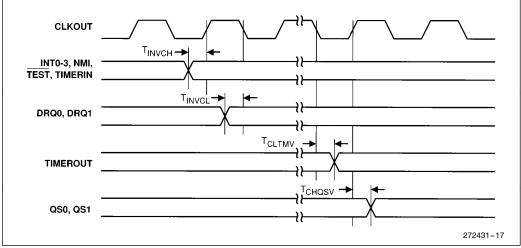


Figure 14. Peripheral and Queue Status Waveforms



AC CHARACTERISTICS (Continued)

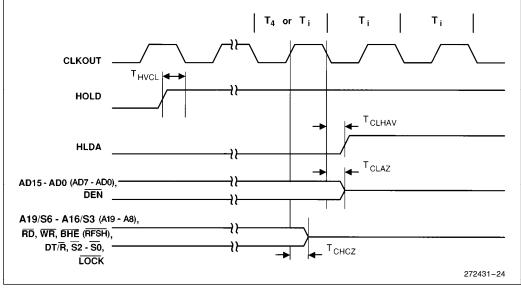


Figure 15. HOLDA/HLDA Waveforms (Entering Hold)

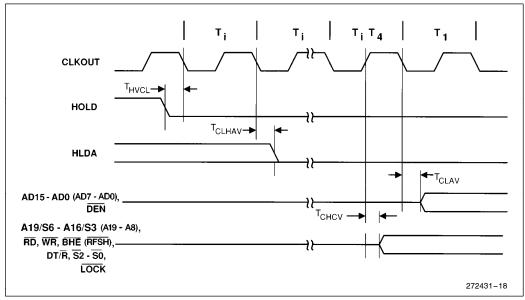


Figure 16. HOLD/HLDA Waveforms (Leaving Hold)

EXPLANATION OF THE AC SYMBOLS

Each timing symbol has from 5 to 7 characters. The first character is always a 'T' (stands for time). The other characters, depending on their positions, stand for the name of a signal or the logical status of that signal. The following is a list of all the characters and what they stand for.

- A: Address
- ARY: Asynchronous Ready Input
- C: Clock Output
- CK: Clock Input
- CS: Chip Select
- CT: Control (DT/\overline{R} , \overline{DEN} , ...)
- D: Data Input
- DE: DEN
- H: Logic Level High
- OUT: Input (DRQ0, TIM0, ...)
- L: Logic Level Low or ALE
- O: Output
- QS: Queue Status (QS1, QS2)
- R: RD Signal, RESET Signal
- S: Status (SO, SI, S2)
- SRY: Synchronous Ready Input
- V: Valid
- W: WR Signal
- X: No Longer a Valid Logic Level
- Z: Float

Examples:

- T_{CLAV} Time from Clock low to Address valid
- T_{CHLH} Time from Clock high to ALE high
- $T_{\mbox{CLCSV}}$ Time from Clock low to Chip Select valid



DERATING CURVES

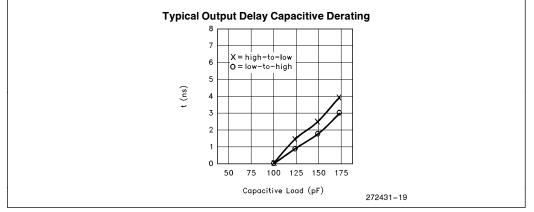


Figure 17. Capacitive Derating Curve

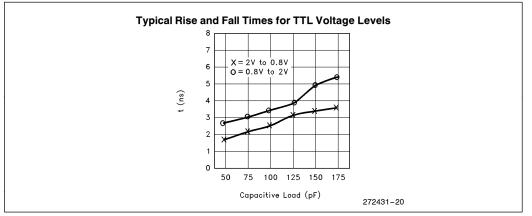


Figure 18. TTL Level Rise and Fall Times for Output Buffers

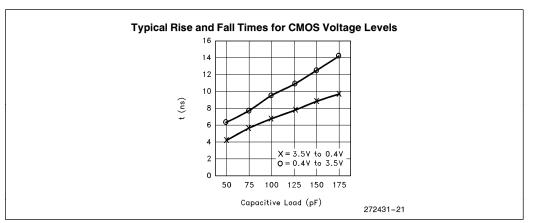


Figure 19. CMOS Level Rise and Fall Times for Output Buffers

80C186XL/80C188XL EXPRESS

The Intel EXPRESS system offers enhancements to the operational specifications of the 80C186XL microprocessor. EXPRESS products are designed to meet the needs of those applications whose operating requirements exceed commercial standards.

The 80C186XL EXPRESS program includes an extended temperature range. With the commercial standard temperature range, operational characteristics are guaranteed over the temperature range of 0° C to + 70°C. With the extended temperature range option, operational characteristics are guaranteed over the range of -40° C to + 85°C.

Package types and EXPRESS versions are identified by a one or two-letter prefix to the part number. The prefixes are listed in Table 10. All AC and DC specifications not mentioned in this section are the same for both commercial and EXPRESS parts.

Prefix	Package Type	Temperature Range
А	PGA	Commercial
Ν	PLCC	Commercial
R	LCC	Commercial
S	QFP	Commercial
SB	SQFP	Commercial
TA	PGA	Extended
TN	PLCC	Extended
TR	LCC	Extended
TS	QFP	Extended

Table 10. Prefix Identification

80C186XL/80C188XL EXECUTION TIMINGS

A determination of program execution timing must consider the bus cycles necessary to prefetch instructions as well as the number of execution unit cycles necessary to execute instructions. The following instruction timings represent the minimum execution time in clock cycles for each instruction. The timings given are based on the following assumptions:

- The opcode, along with any data or displacement required for execution of a particular instruction, has been prefetched and resides in the queue at the time it is needed.
- No wait states or bus HOLDs occur.
- All word-data is located on even-address boundaries (80C186XL only).

All jumps and calls include the time required to fetch the opcode of the next instruction at the destination address.

All instructions which involve memory accesses can require one or two additional clocks above the minimum timings shown due to the asynchronous handshake between the bus interface unit (BIU) and execution unit.

With a 16-bit BIU, the 80C186XL has sufficient bus performance to ensure that an adequate number of prefetched bytes will reside in the queue (6 bytes) most of the time. Therefore, actual program execution time will not be substantially greater than that derived from adding the instruction timings shown.

The 80C188XL 8-bit BIU is limited in its performance relative to the execution unit. A sufficient number of prefetched bytes may not reside in the prefetch queue (4 bytes) much of the time. Therefore, actual program execution time will be substantially greater than that derived from adding the instruction timings shown.



INSTRUCTION SET SUMMARY

Function	Format					80C188XL Clock Cycles	Comments
DATA TRANSFER MOV = Move:							
Register to Register/Memory	1000100w	mod reg r/m			2/12	2/12*	
Register/memory to register	1000101w	mod reg r/m			2/9	2/9*	
Immediate to register/memory	1100011w	mod 000 r/m	data	data if w = 1	12/13	12/13	8/16-bit
Immediate to register	1011w reg	data	data if w = 1]	3/4	3/4	8/16-bit
Memory to accumulator	1010000w	addr-low	addr-high]	8	8*	
Accumulator to memory	1010001w	addr-low	addr-high]	9	9*	
Register/memory to segment register	10001110	mod 0 reg r/m			2/9	2/13	
Segment register to register/memory	10001100	mod 0 reg r/m			2/11	2/15	
PUSH = Push:							
Memory	11111111	mod 1 1 0 r/m			16	20	
Register	01010 reg				10	14	
Segment register	0 0 0 reg 1 1 0				9	13	
Immediate	011010s0	data	data if s=0		10	14	
PUSHA = Push All	01100000				36	68	
POP = Pop:							
Memory	10001111	mod 0 0 0 r/m			20	24	
Register	01011 reg				10	14	
Segment register	0 0 0 reg 1 1 1	(reg≠01)			8	12	
POPA = Pop All	01100001				51	83	
XCHG = Exchange:							
Register/memory with register	1000011w	mod reg r/m			4/17	4/17*	
Register with accumulator	10010 reg				3	3	
IN = Input from:							
Fixed port	1110010w	port			10	10*	
Variable port	1110110w				8	8*	
OUT = Output to:	·						
Fixed port	1110011w	port			9	9*	
Variable port	1110111w				7	7*	
XLAT = Translate byte to AL	11010111				11	15	
LEA = Load EA to register	10001101	mod reg r/m			6	6	
LDS = Load pointer to DS	11000101	mod reg r/m	(mod≠11)		18	26	
LES = Load pointer to ES	11000100	mod reg r/m	(mod≠11)		18	26	
LAHF = Load AH with flags	10011111				2	2	
SAHF = Store AH into flags	10011110				3	3	
PUSHF = Push flags	10011100				9	13	
POPF = Pop flags	10011101				8	12	

Shaded areas indicate instructions not available in 8086/8088 microsystems.

NOTE: *Clock cycles shown for byte transfers. For word operations, add 4 clock cycles for all memory transfers.

80C186XL/80C188XL

INSTRUCTION SET SUMMARY (Continued)

data data if w = 1 data data if w = 1	data if s w =01	Cycles 2 2 2 2 3/10 4/16 3/4	Cycles 2 2 2 3/10* 4/16*	
data if w=1 data]	2 2 2 3/10 4/16	2 2 3/10* 4/16*	
data if w=1 data]	2 2 3/10 4/16	2 2 3/10* 4/16*	
data if w=1 data]	2 3/10 4/16	2 3/10* 4/16*	
data if w=1 data]	3/10 4/16	3/10* 4/16*	
data if w=1 data]	3/10 4/16	3/10* 4/16*	
data if w=1 data]	4/16	4/16*	
data if w=1 data]			
data]	3/4	0/4	1
	- 		3/4	8/16-bit
		3/10	3/10*	
data if $w = 1$	data if s w=01	4/16	4/16*	
		3/4	3/4	8/16-bit
	<u>,</u>			
		3/15	3/15*	
		3	3	
		3/10	3/10*	
data	data if s w=01	4/16	4/16*	
data if w = 1]	3/4	3/4	8/16-bit
	J			
		3/10	3/10*	
data	data if s w=01	4/16	4/16*	
data if w = 1]	3/4	3/4*	8/16-bit
	J			
		3/15	3/15*	
		3	3	
		3/10	3/10*	
		3/10	3/10*	
data	data if s w=01	3/10	3/10*	
data if w = 1]	3/4	3/4	8/16-bit
		3/10	3/10*	
		8	8	
		4	4	
		4	4	
		26-28 35-37		1
			35-37	1
	data if w = 1 data data data data if w = 1 data	data if w = 1 data data data if s w = 01 data if w = 1 data if s w = 01	data data if s w=01 4/16 data if w=1 3/10 data data if s w=01 4/16 data data if s w=01 3/10 data if w=1 3/10 data data if s w=01 3/20 data data if s w=01 3/4 data data data data data data<	data data if s w=01 4/16 4/16* data if w=1 3/4 3/4 3/10 3/10* 4/16* data data if s w=01 4/16 4/16* data data if s w=01 3/4 3/4* data data if s w=01 3/15 3/15* data jata jata jata data jata jata jata jata jata </td

Shaded areas indicate instructions not available in 8086/8088 microsystems.

NOTE: *Clock cycles shown for byte transfers. For word operations, add 4 clock cycles for all memory transfers.



INSTRUCTION SET SUMMARY (Continued)

Function		Fo	rmat		80C186XL Clock Cycles	80C188XL Clock Cycles	Comments
ARITHMETIC (Continued)							
IMUL = Integer multiply (signed):	1111011w	mod 1 0 1 r/m					
Register-Byte					25-28	25-28	
Register-Word Memory-Byte					34-37 31-34	34-37 32-34	
Memory-Word					40-43	40-43*	
IMUL = Integer Immediate multiply (signed)	011010s1	mod reg r/m	data	data if s=0	22-25/ 29-32	22-25/ 29-32	
DIV = Divide (unsigned):	1111011w	mod 1 1 0 r/m					
Register-Byte		•			29	29	
Register-Word					38	38	
Memory-Byte Memory-Word					35 44	35 44*	
IDIV = Integer divide (signed):	1111011w	mod 1 1 1 r/m					
Register-Byte					44-52	44-52	
Register-Word					53-61	53-61	
Memory-Byte Memory-Word					50-58 59-67	50-58 59-67*	
AAM = ASCII adjust for multiply	11010100	00001010			19	19	
AAD = ASCII adjust for divide	11010101	00001010			15	15	
CBW = Convert byte to word	10011000]			2	2	
CWD = Convert word to double word	10011001				4	4	
LOGIC Shift/Rotate Instructions:							
Register/Memory by 1	1101000w	mod TTT r/m			2/15	2/15	
Register/Memory by CL	1101001w	mod TTT r/m			5+n/17+n	5+n/17+n	
Register/Memory by Count	1100000w	mod TTT r/m	count		5+n/17+n	5+n/17+n	
AND = And:		TTT Instruction 0 0 0 ROL 0 0 1 ROR 0 1 0 RCL 0 1 1 RCR 1 0 0 SHL/SAL 1 0 1 SHR 1 1 1 SAR					
Reg/memory and register to either	001000dw	mod reg r/m			3/10	3/10*	
Immediate to register/memory	100000w	mod 1 0 0 r/m	data	data if $w = 1$	4/16	4/16*	
Immediate to accumulator	0010010w	data	data if $w = 1$]	3/4	3/4*	8/16-bit
TEST = And function to flags, no resu	lt:						
Register/memory and register	1000010w	mod reg r/m			3/10	3/10*	
Immediate data and register/memory	1111011w	mod 0 0 0 r/m	data	data if w=1	4/10	4/10*	
Immediate data and accumulator	1010100w	data	data if w = 1]	3/4	3/4	8/16-bit
OR=Or:							
Reg/memory and register to either	000010dw	mod reg r/m			3/10	3/10*	
Immediate to register/memory	100000w	mod 0 0 1 r/m	data	data if w = 1	4/16	4/16*	
Immediate to accumulator	0000110w	data	data if $w = 1$		3/4	3/4*	8/16-bit

Shaded areas indicate instructions not available in 8086/8088 microsystems.

NOTE:

*Clock cycles shown for byte transfers. For word operations, add 4 clock cycles for all memory transfers.

INSTRUCTION SET SUMMARY (Continued)

Function		Fo	rmat		80C186XL Clock Cycles	80C188XL Clock Cycles	Comments
LOGIC (Continued) XOR = Exclusive or:						-	
Reg/memory and register to either	001100dw	mod reg r/m			3/10	3/10*	
Immediate to register/memory	100000w	mod 1 1 0 r/m	data	data if w = 1	4/16	4/16*	
Immediate to accumulator	0011010w	data	data if $w = 1$]	3/4	3/4	8/16-bit
NOT = Invert register/memory	1111011w	mod 0 1 0 r/m		-	3/10	3/10*	
STRING MANIPULATION							
MOVS = Move byte/word	1010010w]			14	14*	
CMPS = Compare byte/word	1010011w]			22	22*	
SCAS = Scan byte/word	1010111w]			15	15*	
LODS = Load byte/wd to AL/AX	1010110w]			12	12*	
STOS = Store byte/wd from AL/AX	1010101w]			10	10*	
INS = Input byte/wd from DX port	0110110w]			14	14	
OUTS = Output byte/wd to DX port	0110111w]			14	14	
Repeated by count in CX (REP/REPE/	REPZ/REPNE/REPI	NZ)					
MOVS = Move string	11110010	1010010w			8+8n	8+8n*	
CMPS = Compare string	1111001z	1010011w			5+22n	5+22n*	
SCAS = Scan string	1111001z	1010111w			5+15n	5+15n*	
LODS = Load string	11110010	1010110w			6+11n	6+11n*	
STOS = Store string	11110010	1010101w			6+9n	6+9n*	
INS = Input string	11110010	0110110w			8+8n	8+8n*	
OUTS = Output string	11110010	0110111w			8+8n	8+8n*	
CONTROL TRANSFER							
CALL = Call:							
Direct within segment	11101000	disp-low	disp-high]	15	19	
Register/memory indirect within segment	11111111	mod 0 1 0 r/m			13/19	17/27	
Direct intersegment	10011010	segmer	nt offset	ן	23	31	
		segment	selector]			
Indirect intersegment	11111111	mod 0 1 1 r/m	(mod ≠ 11)		38	54	
JMP = Unconditional jump:	L		····· · · · · · · · · · · · · · · · ·				
Short/long	11101011	disp-low			14	14	
Direct within segment	11101001	disp-low	disp-high]	14	14	
Register/memory indirect within segment	11111111	mod 1 0 0 r/m		ı	11/17	11/21	
-	11101010		at affaat	ן			
Direct intersegment	11101010	segmer		J	14	14	
		segment	selector	J			
Indirect intersegment	11111111	mod 1 0 1 r/m	(mod \neq 11)		26	34	

Shaded areas indicate instructions not available in 8086/8088 microsystems.

NOTE:

*Clock cycles shown for byte transfers. For word operations, add 4 clock cycles for all memory transfers.



INSTRUCTION SET SUMMARY (Continued)

Function		Format			80C186XL Clock Cycles	80C188XL Clock Cycles	Comments
CONTROL TRANSFER (Continued) RET = Return from CALL:							
Within segment	11000011				16	20	
Within seg adding immed to SP	11000010	data-low	data-high]	18	22	
Intersegment	11001011				22	30	
Intersegment adding immediate to SP	11001010	data-low	data-high]	25	33	
JE/JZ = Jump on equal/zero	01110100	disp		1	4/13	4/13	JMP not
JL/JNGE = Jump on less/not greater or equal	01111100	disp			4/13	4/13	taken/JMP
JLE/JNG = Jump on less or equal/not greater	01111110	disp			4/13	4/13	taken
JB/JNAE = Jump on below/not above or equal	01110010	disp			4/13	4/13	
JBE/JNA = Jump on below or equal/not above	01110110	disp			4/13	4/13	
JP/JPE = Jump on parity/parity even	01111010	disp			4/13	4/13	
JO = Jump on overflow	01110000	disp			4/13	4/13	
JS = Jump on sign	01111000	disp			4/13	4/13	
JNE/JNZ = Jump on not equal/not zero	01110101	disp			4/13	4/13	
JNL/JGE = Jump on not less/greater or equal	01111101	disp			4/13	4/13	
JNLE/JG = Jump on not less or equal/greater	01111111	disp			4/13	4/13	
JNB/JAE = Jump on not below/above or equal	01110011	disp			4/13	4/13	
					4/13	4/13	
JNBE/JA = Jump on not below or equal/above	01110111	disp					
JNP/JPO = Jump on not par/par odd	01111011	disp			4/13	4/13	
JNO = Jump on not overflow	01110001	disp			4/13	4/13	
JNS = Jump on not sign	01111001	disp			4/13	4/13	
JCXZ = Jump on CX zero	11100011	disp			5/15	5/15	
LOOP = Loop CX times	11100010	disp			6/16	6/16	LOOP not taken/LOOF
LOOPZ/LOOPE = Loop while zero/equal	11100001	disp			6/16	6/16	taken
LOOPNZ/LOOPNE = Loop while not zero/equal	11100000	disp			6/16	6/16	
ENTER = Enter Procedure L = 0 L = 1 L > 1	11001000	data-low	data-high	L	15 25 22+16(n-1)	19 29 26+20(n-1)	
LEAVE = Leave Procedure	11001001				8	8	
INT = Interrupt:							
Type specified	11001101	type			47	47	
Туре 3	11001100				45	45	if INT. taken.
INTO = Interrupt on overflow	11001110				48/4	48/4	if INT. not taken
IRET = Interrupt return	11001111				28	28	
BOUND = Detect value out of range	01100010	mod reg r/m			33-35	33-35	

Shaded areas indicate instructions not available in 8086/8088 microsystems.

NOTE: *Clock cycles shown for byte transfers. For word operations, add 4 clock cycles for all memory transfers.

80C186XL/80C188XL

INSTRUCTION SET SUMMARY (Continued)

Function	Format	80C186X Clock Cycles	- 80C188XL Clock Cycles	Comments
PROCESSOR CONTROL				
CLC = Clear carry	1111000	2	2	
CMC = Complement carry	11110101	2	2	
STC = Set carry	1111001	2	2	
CLD = Clear direction	1111100	2	2	
STD = Set direction	1111101	2	2	
CLI = Clear interrupt	1111010	2	2	
STI = Set interrupt	1111011	2	2	
HLT = Halt	11110100	2	2	
WAIT = Wait	10011011	6	6	if $\overline{\text{TEST}} = 0$
LOCK = Bus lock prefix	11110000	2	2	
NOP = No Operation	10010000	з	3	
	(TTT LLL are opcode to processor extension)			

Shaded areas indicate instructions not available in 8086/8088 microsystems.

NOTE:

*Clock cycles shown for byte transfers. For word operations, add 4 clock cycles for all memory transfers.

The Effective Address (EA) of the memory operand is computed according to the mod and r/m fields: if mod = 11 then r/m is treated as a REG field

if mod	=	11 then r/m is treated as a REG field
if mod	=	00 then $DISP = 0^*$, disp-low and disp-
		high are absent
if mod	=	01 then DISP = disp-low sign-ex-
		tended to 16-bits, disp-high is absent
if mod	=	10 then $DISP = disp-high: disp-low$
if r/m	=	000 then $EA = (BX) + (SI) + DISP$
if r/m	=	001 then $EA = (BX) + (DI) + DISP$
if r/m	=	010 then $EA = (BP) + (SI) + DISP$
if r/m	=	011 then $EA = (BP) + (DI) + DISP$
if r/m	=	100 then $EA = (SI) + DISP$
if r/m	=	101 then EA = (DI) + DISP
if r/m	=	110 then EA = (BP) + DISP*
if r/m	=	111 then $EA = (BX) + DISP$

DISP follows 2nd byte of instruction (before data if required)

*except if mod = 00 and r/m = 110 then EA = disp-high: disp-low.

EA calculation time is 4 clock cycles for all modes, and is included in the execution times given whenever appropriate.

Segment Override Prefix

|--|

reg is assigned according to the following:

	Segment
reg	Register
00	ES
01	CS
10	SS
11	DS

REG is assigned according to the following table:

16-Bit (w = 1)	8-Bit (w = 0)
000 AX	000 AL
001 CX	001 CL
010 DX	010 DL
011 BX	011 BL
100 SP	100 AH
101 BP	101 CH
110 SI	110 DH
111 DI	111 BH

The physical addresses of all operands addressed by the BP register are computed using the SS segment register. The physical addresses of the destination operands of the string primitive operations (those addressed by the DI register) are computed using the ES segment, which may not be overridden.

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REVISION HISTORY

This data sheet replaces the following data sheets:

- 272031-002 80C186XL
- 270975-002 80C188XL
- 272309-001 SB80C186XL
- 272310-001 SB80C188XL

ERRATA

An A or B step 80C186XL/80C188XL has the following errata. The A or B step 80C186XL/80C188XL can be identified by the presence of an "A" or "B" alpha character, respectively, next to the FPO number. The FPO number location is shown in Figure 4. An internal condition with the interrupt controller can cause no acknowledge cycle on the INTA1 line in response to INT1. This errata only occurs when Interrupt 1 is configured in cascade mode and a higher priority interrupt exists. This errata will not occur consistently, it is dependent on interrupt timing.

The C step 80C186XL/80C188XL has no known errata. The C step can be identified by the presence of a "C" or "D" alpha character next to the FPO number. The FPO number location is shown in Figure 4.

PRODUCT IDENTIFICATION

Intel 80C186XL devices are marked with a 9-character alphanumeric Intel FPO number underneath the product number. This data sheet (272431-001) is valid for devices with an "A", "B", "C", or "D" as the ninth character in the FPO number, as illustrated in Figure 4.

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- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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